## THE GENERAL RADIO EXPERIMENTER



Transfer-Function and Immittance Bridge Metered Variacs

## COVER



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Published Monthly by the General Radio CompanyVOLUME 33 • NUMBER 5MAY, 1959
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## TYPE 1607-A TRANSFER-FUNCTION AND IMMITTANCE BRIDGE <br> NEW FUNCTIONS, NEW NAME, AND NEW TEST MOUNTS

An unusual new instrument, identified as the Type 1607-A Transfer-Function Meter, was described in this publication a little over one year ago. ${ }^{1}$ It could measure all the complex transfer functions ${ }^{2}$ of three- and four-terminal ${ }^{3}$ devices and networks, such as transistors, vacuum tubes, amplifiers, filters, and attenuators, over the $60: 1$ frequency range from 25 Mc to 1500 Mc .

## New Functions

Stimulated by comments of people seeing the instrument for the first time, e.g.,-"That's fine, but isn't there some way of making it measure two-terminal impedances and admittances, too? Then it would measure everything," we looked further and found a simple way to do just this. ${ }^{4}$ Although the changes necessary to incorporate the added functions involved cutting a fourth set of slots in
the instrument's main junction block and the addition of a new indicator assembly, we were fortunately able to catch the first production lot of instruments just in time to include these new features, starting with the first instrument sold. Therefore, all instruments in use are up to date, except that on the earliest units the engraving shows the old name. The instrument will now measure the input or output impedance or admittance of two-, three-, or fourterminal networks with de bias supplied to all terminals and with three- and fourterminal networks terminated in either an rf short or open circuit.

[^0]Figure 1. View of the Transfer-Function and Immittance Bridge with Transfer-Function indicator in place. Interchangeable Immittance Indicator is shown in foreground.


## New Name

With the capabilities of the instrument increased to cover many additional applications, the old name, "TransferFunction Meter," was not completely descriptive. The new name is "TransferFunction and Immittance Bridge," the word "Immittance" denoting both impedance and admittance. Because of its convenience, this word is gradually coming into more common use in connection with transmission lines, networks, and certain types of measuring instruments, such as the slotted line.

The change of the last word from "Meter" to "Bridge" is intended to improve further the descriptive accuracy of the name. Passive, null-typecircuits used with generator and detector to measure accurately the real and imaginary components of an unknown in terms of resistive and reactive standards are commonly called "bridges," whether or not the classic, bridge, diamond form is apparent without topological juggling.

## Interchangeable Indicators

'Two different indicator units, shown in Figures 2 and 3, are furnished with
the bridge, one for transfer-function measurements and the other for immittance measurements. Each is an assembly of a casting with three rotatable loop units, control-indicator arms, and calibrated scales. They are held in place by four screws and are easily interchanged. Locating pins permanently preserve alignment and factory calibration.

## Circuit for Immittance Measurements

The operating principles and circuit for transfer-function measurements were fully described in the earlier article, ${ }^{1}$ to which reference is made for basic description and features. For immittance measurements with the Immittance Indicator (Figure 4), there are still three loops coupled to three coaxial lines, two of which are terminated, respectively, in a standard conductance and a standard susceptance, but the third loop couples to the bottom line (labeled "Network Output') instead of to the righthand line (labeled "Network Input"). In the schematic diagram of Figure 4, the circuit is set up for measuring the output immittance of a four-terminal network. To measure network input im-

Figure 2. View of the two indicators. Calibrations are normalized with respect to coaxial line characteristic impedance ( 50 ohms) and admittance ( 20 millimhos).



Figure 3. Rear view of indicator units showing different loop locations and consequent differences in scale plate shape.
mittances, the network is simply reversed. Note that the lower line, though labeled "Network Output" because of its use during transfer-function measurements, actually drives the network during immittance measurements. The upper line, labeled "Network Input" because of its use during transfer-function measurements, acts as either a short or open circuit at the other end of the network during immittance measurements and has no other coupling to the circuit, except to provide de bias if required.

For measurements on two-terminal, grounded immittances, the unknown
network is connected to the lower ("Output") terminals, and the upper line (labeled "Network Input") is not used at all.

This circuit for immittance measurements is the same as that used in the Type 1 ( $602-13$ Admittance Meter. ${ }^{5}$ With the lower line (labeled "Network Output") set to a half wavelength or an integer multiple thereof, the instrument measures admittance. With the line set to a quarter wavelength or odd multiple,

[^1]Figure 4. Schematic diagram of the circuit for immiffance measurement. For a diagram of the circuit for transfer-function measurement, see previous article. ${ }^{1}$

the instrument measures impedance. The scales are calibrated in normalized components, from 0 to 1 , with a multiplier from 1 to $\infty$. For impedance measurements, the reference is 50 ohms, and for admittance measurements, 20 mmhos. The Transfer-Function and Immittance Bridge can measure everything that the Admittance Meter can measure, including reflection coefficient and VSWR of transmission lines and antemnas. In addition, it has the built-in, calibrated, adjustable line for directreading immittance measurements, the second, short-circuited, calibrated, adjustable line for proper termination of four-terminal networks during input and output immittance measurements, and provisions for biasing active devices or networks. However, the Admittance Meter will, no doubt, still be preferred in a number of instances for two-terminal measurements because of its lower price, smaller size, and somewhat better basic accuracy ( $3 \%$ vs. $5 \%$ ).

## New Transistor Mounts

At very-high and ultra-high frequencies, the method of connecting an unknown device to a measuring instrument of any kind is critical. Reproducible answers can be obtained in different measurements by different people using different equipment only if the same, standard method of making comections is used in all cases, with details of configuration and dimension being precisely the same. Furthermore, the necessity of



Figure 6. Sketch of connections to transistor, showing the reference points of measurement.
applying bridge voltages or currents to transistors or other active devices, of accurately compensating stray capacitances and inductances, and of suppressing spurious oscillations makes the de$\operatorname{sign}$ of suitable mounts more than a minor job, even for an engineer skilled in vhf-uhf design techniques.

To help avoid these problems in transistor measurements, standard mounts have been designed, two of which are presently available and two more which are approaching completion in development. Additional types will be added from time to time in response to user demand. Those available now are for JETEC basings, 0.200 -inch-pin-circle triode with common base (16(0)-P101) or common emitter ( $1607-\mathrm{P} 102$ ). Those in development are for 0.200 -inch-pincircle tetrodes and (0.100-inch-pin-circle triodes with common hase. Leads of units to be measured can be any length between $3 / 32$ and 5 í inch, and lead diameters up to 0.035 inch can be accommodated. In the Transfer-Function and Immittance Bridge all characteristics of a given transistor with a given common electrode are measured with a single mount, thus insuring consistency of results at high frequencies.

These transistor mounts incorporate several refinements that result in accurate and reproducible measurements:

Figure 5. Two views of the Type 1607-P 101 Transistor Mount showing the damper unit projecting from the side. In the right-hand view the lead alignment holes can also be seen.


Figure 7. View of the Type 1607-P 201 Tube Mount with tube and shield installed and damper unit projecting from side. Binding posts af left are for heater connections.
(a) The reference point of measurement on the transistor leads is only $1 / 16^{\prime \prime}$ from where they emerge from the header, as shown by Figure 6. Therefore, the measured characteristics are those of the transistor elements in their housing and with $1 / 16^{\prime \prime}$ leads. This measurement environment is very close to the best that can practically be done in actual circuit use of transistors.
(b) The input and output lines leading to the reference plane are accurately compensated to maintain a 50 -ohm characteristic impedance level with very low reflections due to discontinuities.
(c) A removable 50 -ohm resistor, with bias blocking capacitor, is supplied to suppress spurious oscillations. This resistor is shunted across either the input or the output of a transistor, depending on the type of measurement being made, and has no adverse effect on measurement accuracy.
(d) The input and output circuits within the mounts are very well shielded, so that coupling between them external to the transistor is negligible.

Transistors with 0.072-inch-pin circles will be easily measurable in the $0.100-$ inch-pin-circle mount (available later) if the leads are bent the slight amount
required, by use of the lead alignment holes provided in the top of the mount.

Figure 5 is a photo of Type 1607-P101 Transistor Mount.

## Tube Mount

One tube mount is available so far. It is designed for common-cathode measurements on seven-pin miniature tubes such as 6AF4, 6AF4A, 6AN4, 6'T4, and other tubes having the same pin connections. The tube is measured in the socket of the mount, so that measured values will include socket effects and will be those of greatest use in circuit design. The Type 1607-T'201 Tube Mount, with tube and shield installed, is shown in Figure 7.

## Typical Measurements

With this instrument direct measurements can be made of the parameters of commonly used transistors, vacuum tubes, and passive networks. T'ransistors can be measured in either the commonbase or common-emitter connection; and a complete set of measurements can be made in either connection without calculation of any of the parameters from measurements made in another connection. This factor is important at high frequencies, where comection changes can cause changes in the effects of stray capacitances and inductances.

The chart on page 8 shows a typical set of measurements made on a highfrequency transistor. All the values were directly measured with the exception of the $h_{o}$ parameters. For the $h_{o}$ measurement, the output admittance must be determined with the input circuit open circuited, a condition which is easily obtained with the bridge. However, with the open-circuit connection, the damping units cannot be used, and in some cases regeneration or oscillation can occur. In
these cases, $h_{o}$ can easily be calculated from the formula:

$$
h_{o}=Y_{22}+\frac{h_{f} h_{r}}{h_{i}}
$$

The variations in some of the above transistor parameters with collector voltage are plotted in Figure 8. Figure 9 shows measured values of forward cur-rent-transfer ratio for a diffused-base transistor. Figure 10 shows the results of measurements of the short-circuit output admittance, $Y_{22}$, on a similar transistor.

The extrinsic base resistance, $r_{b b^{\prime}}$, of a transistor is often determined ${ }^{6}$ from measurements of the common-emitter input impedance with the collector short circuited, $h_{i e}$. In this case, the $r_{b b^{\prime}}$ is approximately equal to the input resistance obtained at a frequency at which the reactance is zero. Figure 11 shows a plot of $h_{i e}$ measured on a relatively low-fre-
quency transistor, indicating a base resistance of 27 ohms. At frequencies above the zero-reactance point, the reactance becomes positive owing to the inductance of the leads inside the transistor body and that of the short length of pin between the seal and the point at which the measurements are made. At much higher frequencies, this lead inductance can be in paralled resonance with the stray capacitance to the shell and ground, as shown in Figure 11.

In high-frequency transistors, the zero-reactance point occurs at a much higher frequency, and the impedance at this point may be affected by stray lead reactances. A typical measurement is shown in Figure 12. Measurements were also made on a slotted line in order to check the values measured on the Transfer-Function and Immittance
612. I'. Abraham and IR. J. Mirkpatrick, "Transistor Characterization at VHF," Proc. Nat. Elec. Conf. 13, pp. 385-402, 1957.

NETWORK PARAMETER MEASUREMENTS ON A HIGH-FREQUENCY TRANSISTOR AT 300 Mc
FREQUENCY $=300 \mathrm{Mc}, \mathrm{V}_{\mathrm{cb}}=-4.5 \mathrm{v}, \mathrm{I}_{\mathrm{c}}=1.0 \mathrm{mo}$, SHELL GROUNDED

| COMMON BASE |  |  | COMMON EMITTER |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | HYBRID | $\begin{gathered} \text { SC } \\ \text { ADMITTANCE } \end{gathered}$ mmhos | HYBRID | $\begin{gathered} \text { SC } \\ \text { ADMITTANCE } \end{gathered}$ mmhos |  |
| $0.79-j 0.53$ | $\begin{gathered} h_{f \mathrm{~b}} \\ -0.79+j 0.53 \end{gathered}$ | $\begin{gathered} Y_{21 b} \\ -3.4+j 10.2 \end{gathered}$ | $\begin{gathered} h_{\mathrm{fe}} \\ -0.68-\mathrm{j} 1.5 \end{gathered}$ | $\begin{gathered} Y_{2 l e} \\ 2.0-j 12.0 \end{gathered}$ | $\begin{gathered} \beta_{\mathfrak{f}} \\ -0.68-\mathrm{j} 1.5 \end{gathered}$ |
| $0.32-j 0.18$ | $\begin{gathered} h_{\mathrm{rb}} \\ 0.04+\mathrm{j} 0.14 \end{gathered}$ | $\begin{gathered} \hline Y_{12 \mathrm{~b}} \\ -1.4-\mathrm{j} 1.0 \end{gathered}$ | $\begin{gathered} \mathrm{h}_{\mathrm{re}} \\ 0.12+\mathrm{j} 0.09 \end{gathered}$ | $\begin{gathered} Y_{12 e} \\ -0.4-j 1.0 \end{gathered}$ | $\begin{array}{\|c} \beta_{\mathrm{r}} \\ -0.215-\mathrm{j} 0.02 \end{array}$ |
|  | $\begin{gathered} \mathrm{h}_{\mathrm{ib}} \\ \begin{array}{c} 67.0+j 53.8 \\ \text { ohms } \end{array} \end{gathered}$ | $\begin{gathered} Y_{11 \mathrm{~b}} \\ 9.1-j 6.9 \end{gathered}$ | $\begin{gathered} \mathrm{h}_{\mathrm{ie}} \\ 115-\mathrm{j} 75 \\ \text { ohms } \end{gathered}$ | $\begin{gathered} Y_{11 e} \\ 5.9+j 4.1 \end{gathered}$ |  |
|  | $\begin{gathered} \mathrm{h}_{\mathrm{ob}} \\ 0.2+j 4.25 \\ \text { mmhos } \end{gathered}$ | $\begin{gathered} Y_{22 b} \\ 1.8+j 4.2 \end{gathered}$ | $\begin{gathered} h_{\mathrm{oe}} \\ 3.2+j 3.0 \\ \text { mmhos } \end{gathered}$ | $\begin{gathered} Y_{22 e} \\ 1.9+\mathrm{j} 4.3 \end{gathered}$ |  |




Figure 9. Plot of $\alpha$, or -hfb, versus frequency for a diffused base fransistor.


Figure 11. Plot of input reactance versus input resistance, with output short circuited, for a low-frequency transistor.


Figure 8. Variation of parameters of a diffused-base transistor as a function of collector voltage.


Figure 10. Plot of short-circuit output admittance as a function of frequency for a diffused-base transistor.


Figure 12. Plot of inpuf reactance versus inpuif resistance, with output short circuited, for a high-frequency transistor. Comparison with slotted-line measurements.

Nots: All schematics on this page show rf connections only. with biasing connections omitted.

Bridge. These measurements are plotted on the same figure, and it is evident that they agree very closely with the Trans-fer-Function and Immittance Bridge measurements.

## Advantages of the Transfer Function and Immittance Bridge

The Transfer-Function and Immittance Bridge has a number of very important advantages over other methods of measuring transistor characteristics in the VHF-UHF range.
(a) All measurements are made directly, with the transistor operating in the proper environment as defined by the parameter being measured. In most cases no calculations are required to obtain any desired short-circuit or opencircuit input, output, or transfer function. Direct measurements save time and avoid deterioration of measurement accuracy.
(b) All input, output, and transfer measurements on a given transistor with a given common electrode are made with the same mount, so that consistency between these different functions is assured. Furthermore, standard mounts are available and are not a design problem to the user.
(c) The unusually wide frequency

range from 25 Mc to 1500 Mc is valuable in most applications and is of particular interest for today's new commercial transistors.
(d) The bridge can be operated with a very low rf level on the unknown, which is essential for the measurement of transistors and other nonlinear devices.
(e) First impressions notwithstanding, the bridge is very simple. The initial appearance of complexity is due to the large number of different things that it can measure, but each of these things by itself is measured in a straightforward and simple manner.

The bridge is completely passive, with stability of calibration dependent only on permanent, physical dimensions.

Finally, the instrument makes basic measurements of circuit characteristics that have been in use since the beginning of radio and that will continue to be used indefinitely into the future of electronics. Currently its most popular use is for the measurement of transistors, but its ability to measure any network, active or passive, indicates a much wider field of application.

## Acknowledgment

The authors wish to acknowledge the contributions of leter D. Strum to the development of this instrument.

- W. R. Tiitrston R. A. Soderman


## SPECIFICATIONS

Frequency Range: 25 to 1500 Mc , with reduced accuracy above 1000 Mc and when flexible cable is used in the lines. The use of this cable is required at frequencies below 150 Mc and is optional at other frequencies.

Figure 13. View of the instrument storage box with accessories that are supplied with the Type 1607-A Transfer-Function and Immittance Bridge.

Measurement Range:
Voltage and Current Ratios
(IR) $0-30$
$2.5(1+\sqrt{R}) \%+0.025$
Transimpedance ( $Z_{21}$ )
()-1500 ohms $2.5\left(1+\sqrt{\frac{Z_{21}}{50}}\right) \%+1.25 \mathrm{ohms}$

Transadmittance ( $Y_{21}$ )
()-fio) $)$ mmhos $2.5\left(1+\sqrt{\frac{Y_{21}}{20}}\right) \%+0.5 \mathrm{mmho}$

Impedance ( $Z_{11}$ )
() -1000 ohms $2.0\left(1+\sqrt{\frac{Z_{11}}{50}}\right) \%+1.0 \mathrm{ohm}$

Admittance ( $Y_{11}$ )
0-400 mmhos $2.0\left(1+\sqrt{\frac{Y_{11}}{20}}\right) \%+0.4$ mmho
DC Bias: Terminals are provided for introducing de: bias from external sources. Maximum bias rurrent, 100 mat ; maximum bias voltage, 4()) volts.

## Accuracy:

(up to 1000 Mc )

Accessories Supplied: Range-Extension Unit; Transfer-Function Indicator; Immittance Indicator; 6 terminations (open, short, matched, etc.); standards; $10-\mathrm{dl}$, attemmator; 8 air lines (21.5 and 43 cm ); 3 U -line sections; const.antimpedance adjustable line; a special tee; 10 patch cords; carrying case with storage spate for instrument and accessories.
Accessories Required: Generator, detector, and mount for unknown device. Unit Oscillators and Type DNT Detectors are recommended. For coaxial adaptors, see latest General Radio Cittalog. See below for mounts available.
Other Accessories Available: Type 1607-IP101 Transistor Mount for JETEC-30 base arrangement, grounded hase. TYpe 1607-P102 Transistor Mount for JETEC-30 base arrangement, grounded emitter. Type 1607-P201 Tube Mount, 7 -pin miniature, grounded-cathode, for 6AF4, 6AF4A, and other tubes with same conmertions.
Case: The instrument, with accessories, is mounted in a wooden carrying and storage case. Dimensions: Case - $111 / 4 \times 141 / 2 \times 40$ inches.
Net Weight: 63 pounds.

| Type |  | Corle Word | Price |
| :---: | :---: | :---: | :---: |
| 1607-A | Transfer-Function and Immitance Bridge | HYidita | \$1665.00 |
| 1607-P101 | Transistor Mount (JETEC-30, grounded base) | TKANSMOUNT | 60.00 |
| 1607-P 102 | Transistor Mount (JETEC-30, grounded emitter) | TOPICMOUNT | 60.00 |
| 1607-P201 | Tube Mount, 7-pin miniature, grounded cathode | TUBESMOUNT | 75.00 |

U. S. Patent No, 2,5-48,457.

## NEW METERED VARIACS, TYPES W5MT3A, W5MT3W

The usefulness of the Variac ${ }^{\sqrt{6}}$ autotransformer as a laboratory tool can be considerably enhanced by the inclusion of meters in the assembly so that voltage, current, or power measurements can be made directly without the necessity of finding, and comnecting, external meters. To this end, General Radio offers two instruments, similar in appearance and construction, and differing only in one respect. The Type W5MTT3A Metered Variac reads volts and amperes; the Type W5atsow Metered Variac reads volts and watts; both are metered in the output or load circuit.

The metal case houses a Type W5

Variac, the meters, a current transformer, and the necessary switching and meter shielding. This latter is sufficiently effective to reduce the Variae stray field to a point permitting an over-all accuracy of $3 \%$ (full scale) with $2 \%$ meters. Connections are made through a three-wire cord (line) and a three-wire outlet (load). A double-pole off-on switch disconnects the instrument from both sides of the line in the off position. A make-beforebreak range switch permits switching under load of the dual scale ammeter or wattmeter, as the case may be, from 1 ampere to is amperes, full scale, or from 150 watts to 750 watts, full scale,

respectively. Current-coil circuit and, hence, load circuits are fused for 1 and 5 amperes in the W5MT3A (ammeter) model and for 2 and 5 amperes in the W5MT3W (wattmeter) model.


The finish matches standard W-line Variacs. The case is equipped with a convenient carrying handle. A net weight of $113 / 4$ pounds assures ready portability.

## SPECIFICATIONS

Frequency: 50-6() rycles.
Input Voltage: $11 \%$.
No Load Loss ( 60 eycles) : 9 watts.
Output Voltage: 0-135 (0-1:5) voltmeter).
Output Current: (W5MT3A) Two ranges $0-1$, 0-5 amperes.
Output Wats: (W5MT3W) 'l'wo ranges - 0-150, 0-750 watts.
Meter Accuracies: $\pm 3 \%$ of full scale.
Switching: OFF-ON, two-pole switch disconnecty assembly from line in "OFF" position.

Meter RANGE, HICH-LOW, make-heforebreak to permit switching under load.

Terminals: Iine - 3 -wire cord and plug.
Latad - 3-wire outlet receptasele (will accept paralled 2 -wirr plug).
Fusing: W5MTBA - 1 ampere, low range. 5 amperes, high rinnge.
W5M'T'3W - ? amperes, low range. 5 amperes, high rathge.
Angle of Rotation: $325^{\circ}$.
Driving Torque: 30-60) oz.-in.
Case Dimensions: $9^{15} / 6^{\prime \prime}$ high, $63 / 4^{\prime \prime}$ wides, $63 / 8^{\prime \prime}$ (deep) and handle.
Nol Weight: $113 / 4$ polnnds.

| T!/pp |  | Code Word | Price |
| :---: | :---: | :---: | :---: |
| W5MT3A | Matered Variac (voltmeter, ammeter) | cabal. | \$ 85.00 |
| W5MT3W | Metered Variac (voltmeter, waltmeter) | CABOB | 110.00 |

[^2]General Radio Company


[^0]:    1W. R. Thurston, R.A. Soderman, " A Tramsfer-Function Meter for the VIIF-TH1 Ramge, " General Radio Experimenter, Vol. 32, No. 10, March, 195s, pp. 3-1.5.
    2 Forward and reverse transabmittance, transimpedance, transfer voltage ratio, and transfer current ratio.
    $3^{3}$ aving one input terminal and one output terminal grounded.
    4 Not " everything," of course - just 2, 3, and 4-terminal networks.

[^1]:    ${ }^{5} \mathrm{~W}$. . R. Thurston." A Dirert-Reading Impedance-Measuring Instrument for the L-H-F Range," General Radio Experimenter, Vol. 24, No. 12, May, 1950, pp. 1-7.
    R. A. Soxlerman. "Improverl Acouracy and Convenience of Measurements with Type 1602-B Admittance Meter in VIIF-I‘HE Bancls," Genernl Radio Experimenter, Vol. 28, No. 3. August. 19-̄3, pe. 1-6.

[^2]:    Patent applied for

